

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors





1. General description

Planar passivated high commutation three quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series C" triac will commutate the full rated RMS current at the maximum rated junction temperature without the aid of a snubber.

2. Features and benefits

- 3Q technology for improved noise immunity
- High blocking voltage capability
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- Less sensitive gate for high noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only

3. Applications

- General purpose motor control circuits
- Home appliances
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

4. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4; Fig. 5}$ | - | - | 25 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 107 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 4 | A |
| Static char | acteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$ | - | - | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | - | 35 | mA |





BTA204-600C

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|-----------|--|-----|-----|-----|------|
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; | - | - | 35 | mA |
| | | T _j = 25 °C; <u>Fig. 7</u> | | | | |

5. Pinning information

| Table 2. | Pinning | information | <u></u> | |
|----------|---------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2-T1 |
| 2 | T2 | main terminal 2 | | G sym051 |
| 3 | G | gate | | |
| mb | T2 | mounting base; main terminal 2 | | |
| | | | TO-220AB (SOT78) | |

6. Ordering information

Table 3.Ordering information

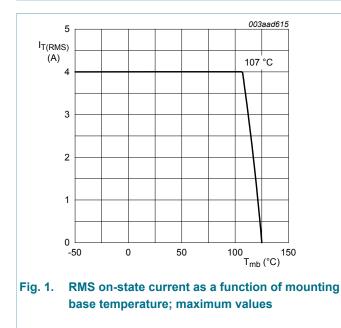
| Type number | Package | | | | |
|----------------|----------|--|---------|--|--|
| | Name | Description | Version | | |
| BTA204-600C | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | |
| BTA204-600C/DG | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | |

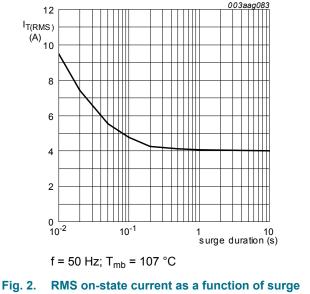
7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

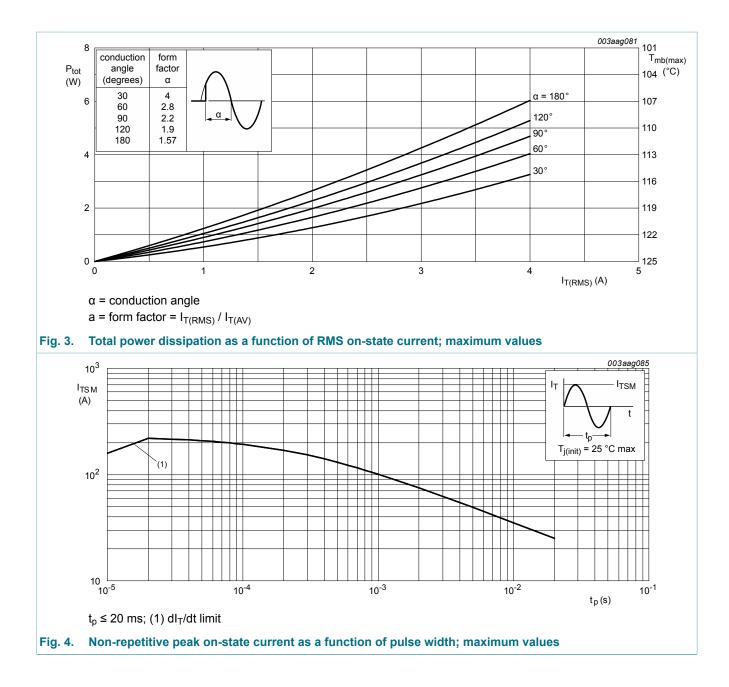
| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|--|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 107 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | 4 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u> | - | 25 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$ | - | 27 | A |
| l ² t | I2t for fusing | t _p = 10 ms; SIN | - | 3.1 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 6 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |





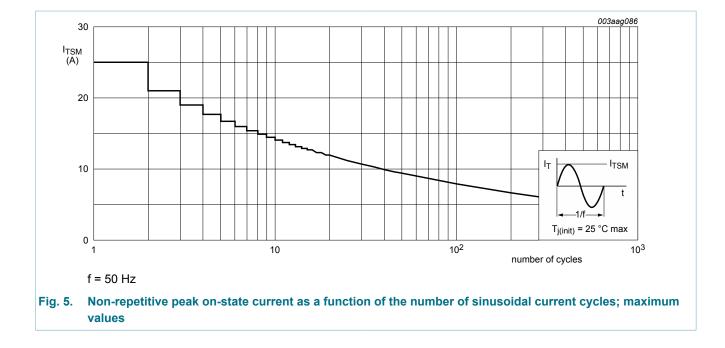
duration; maximum values

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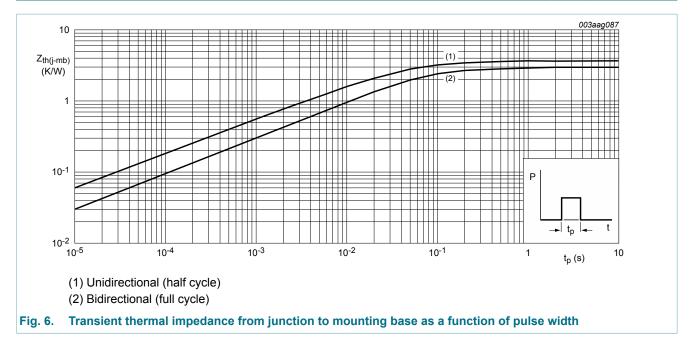
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8. Thermal characteristics

| Table 5. The | rmal characteristics | | | | | |
|-----------------------|---|---------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance | full cycle; Fig. 6 | - | - | 3 | K/W |
| | from junction to mounting base | half cycle; <u>Fig. 6</u> | - | - | 3.7 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



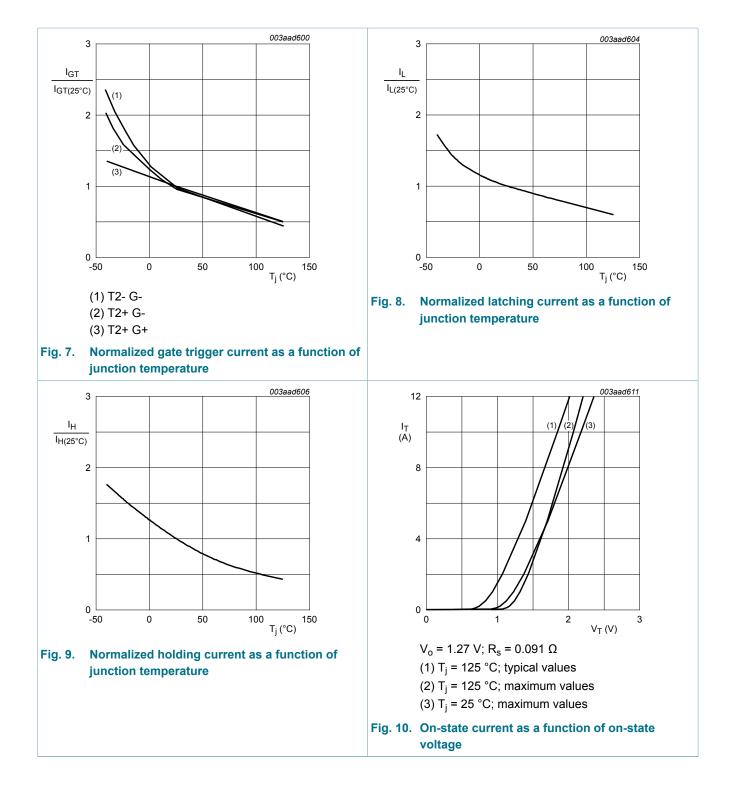
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9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|------|-----|-----|------|
| Static char | acteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$ | - | - | 35 | mA |
| | | V_D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | - | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | - | 35 | mA |
| ΙL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 20 | mA |
| | | V_D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 30 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u> | - | - | 20 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 20 | mA |
| V _T | on-state voltage | I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.4 | 1.7 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic cl | haracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 1000 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 4 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit | 3 | - | - | A/ms |

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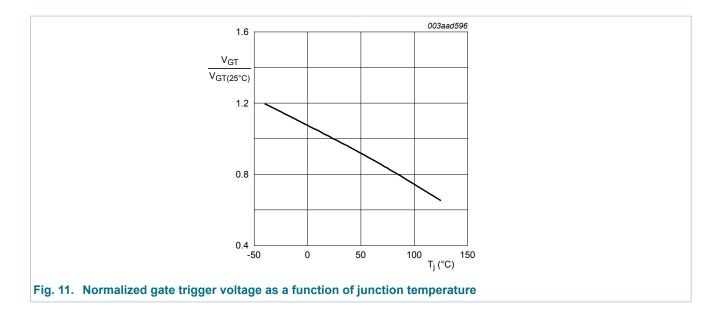


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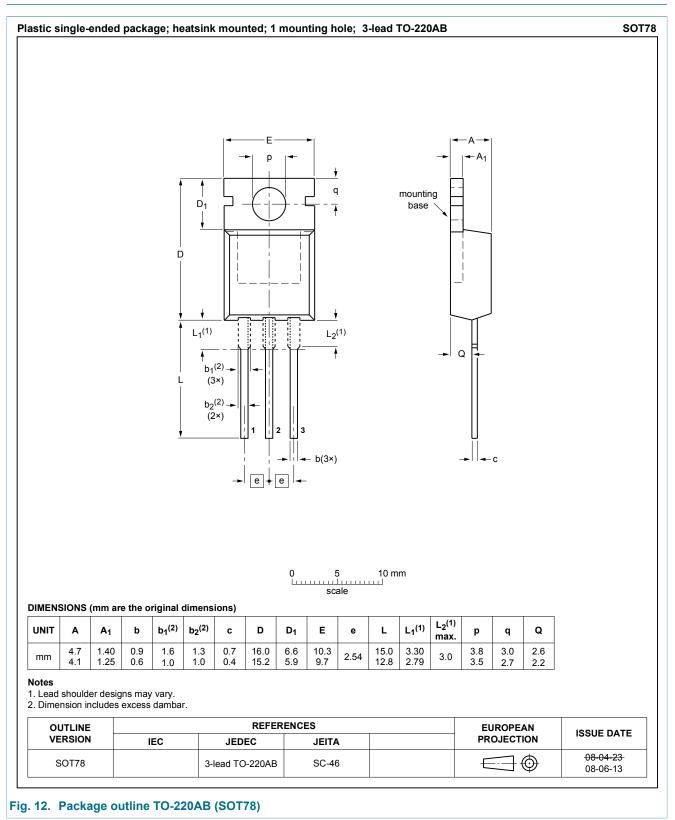
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10. Package outline



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| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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12. Contents

| 1 | General description | 1 |
|------|-------------------------|----|
| 2 | Features and benefits | 1 |
| 3 | Applications | 1 |
| 4 | Quick reference data | 1 |
| 5 | Pinning information | 2 |
| 6 | Ordering information | 2 |
| 7 | Limiting values | 3 |
| 8 | Thermal characteristics | 6 |
| 9 | Characteristics | 7 |
| 10 | Package outline | 10 |
| 11 | Legal information | 11 |
| 11.1 | Data sheet status | 11 |
| 11.2 | Definitions | 11 |
| | | |
| 11.3 | Disclaimers | 11 |

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BTA204-600C